

# MSD42WT1G, NSVMSD42WT1G

## NPN High Voltage Transistors

This NPN Silicon Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

### Features

- These Devices are Pb-Free, Halogen Free and are RoHS Compliant
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )

Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{(BR)CBO}$	300	V
Collector-Emitter Voltage	$V_{(BR)CEO}$	300	V
Emitter-Base Voltage	$V_{(BR)EBO}$	6.0	V
Collector Current – Continuous	$I_C$	150	mA

### THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation (Note 1)	$P_D$	450	mW
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	274	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### ELECTRICAL CHARACTERISTICS

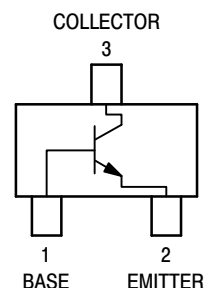
Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage ( $I_C = 1.0\text{ mA}, I_B = 0$ )	$V_{(BR)CEO}$	300	-	V
Collector-Base Breakdown Voltage ( $I_C = 100\ \mu\text{A}, I_E = 0$ )	$V_{(BR)CBO}$	300	-	V
Emitter-Base Breakdown Voltage ( $I_E = 100\ \mu\text{A}, I_C = 0$ )	$V_{(BR)EBO}$	6.0	-	V
Collector-Base Cutoff Current ( $V_{CB} = 200\text{ V}, I_E = 0$ )	$I_{CBO}$	-	0.1	$\mu\text{A}$
Emitter-Base Cutoff Current ( $V_{EB} = 6.0\text{ V}, I_B = 0$ )	$I_{EBO}$	-	0.1	$\mu\text{A}$
DC Current Gain (Note 2) ( $V_{CE} = 10\text{ V}, I_C = 1.0\text{ mA}$ ) ( $V_{CE} = 10\text{ V}, I_C = 30\text{ mA}$ )	$h_{FE1}$ $h_{FE2}$	25 40	- -	-
Collector-Emitter Saturation Voltage (Note 2) ( $I_C = 20\text{ mA}, I_B = 2.0\text{ mA}$ )	$V_{CE(sat)}$	-	0.5	V

1. FR-4 @ 10 mm<sup>2</sup>, 1 oz. Copper traces.
2. Pulse Test: Pulse Width  $\leq 300\ \mu\text{s}$ , D.C.  $\leq 2\%$ .



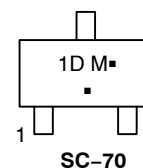
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SC-70 (SOT-323)  
CASE 419  
STYLE 3

### MARKING DIAGRAM



1D = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package  
(Note: Microdot may be in either location)

### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MSD42WT1G	SC-70 (Pb-Free)	3000 / Tape & Reel
NSVMSD42WT1G	SC-70 (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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## TYPICAL CHARACTERISTICS

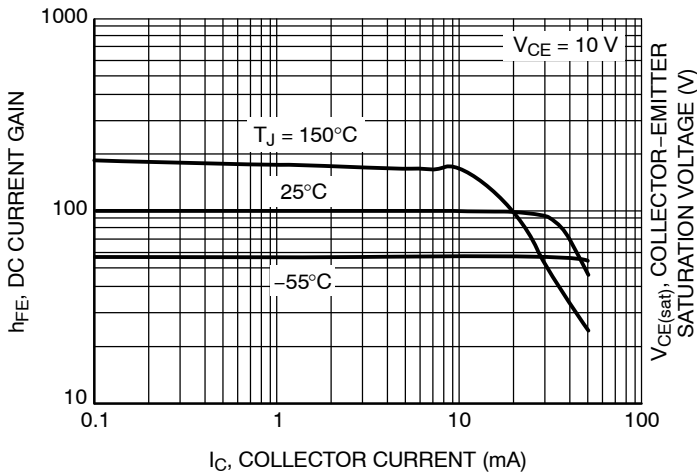


Figure 1. DC Current Gain

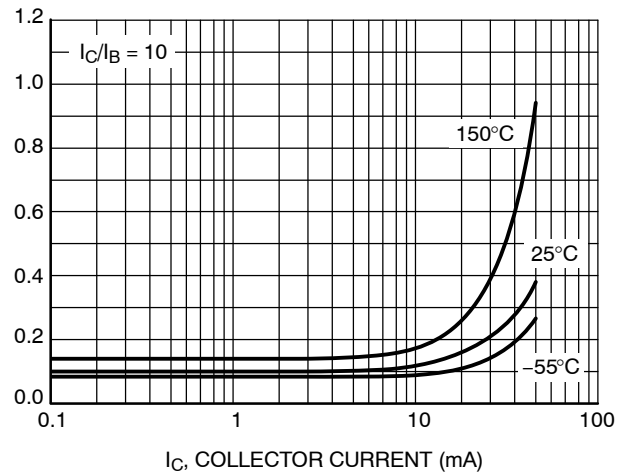


Figure 2. Collector-Emitter Saturation Voltage vs. Collector Current

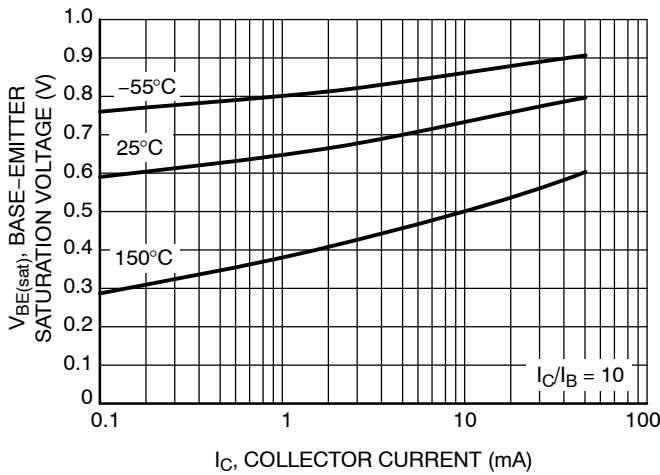


Figure 3. Base-Emitter Saturation Voltage vs. Collector Current

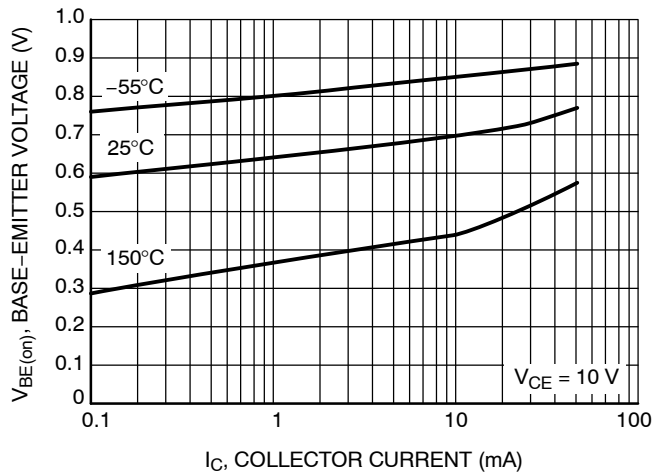


Figure 4. Base-Emitter On Voltage vs. Collector Current

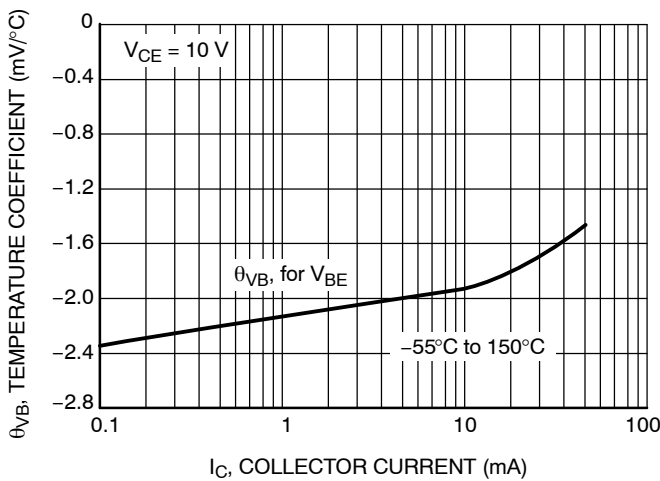


Figure 5. Base-Emitter Temperature Coefficient

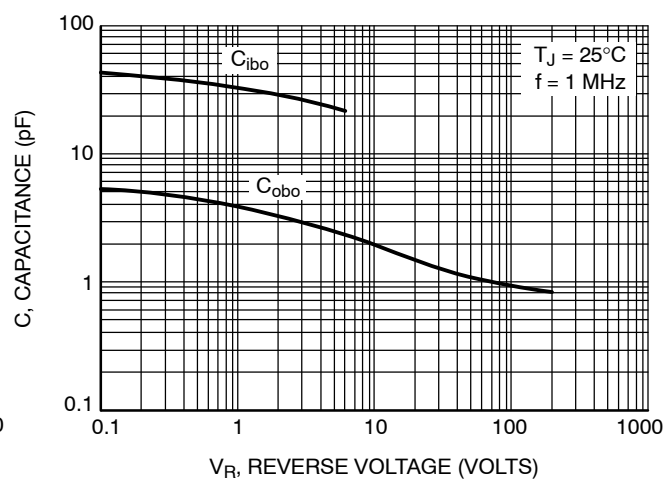


Figure 6. Capacitance

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## TYPICAL CHARACTERISTICS

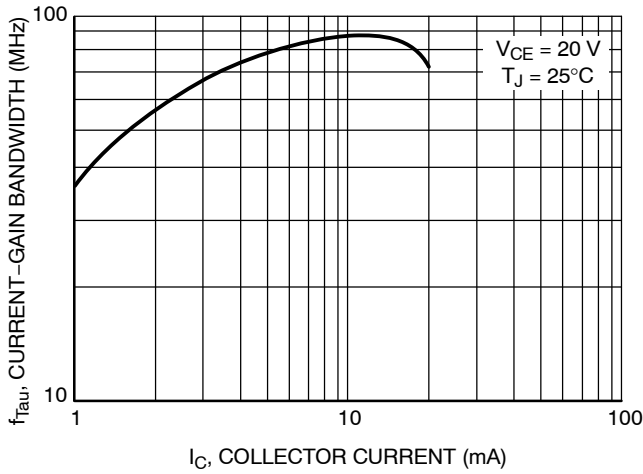


Figure 7. Current-Gain — Bandwidth Product

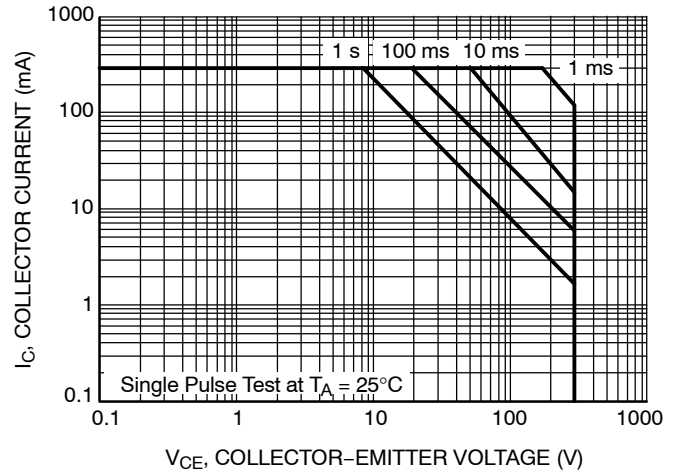


Figure 8. Safe Operating Area

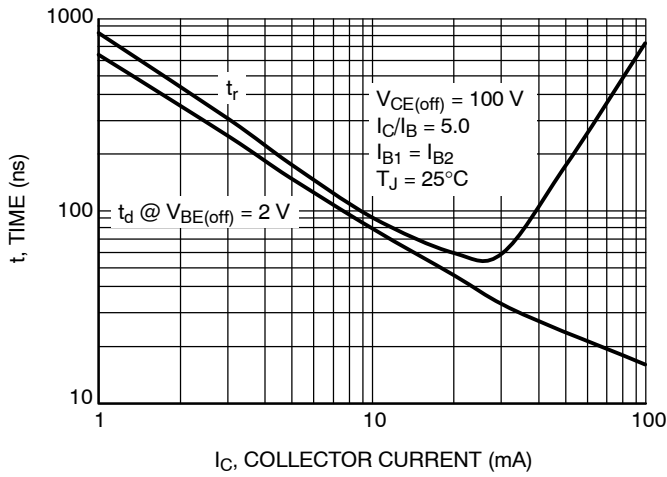


Figure 9. Turn-On Time

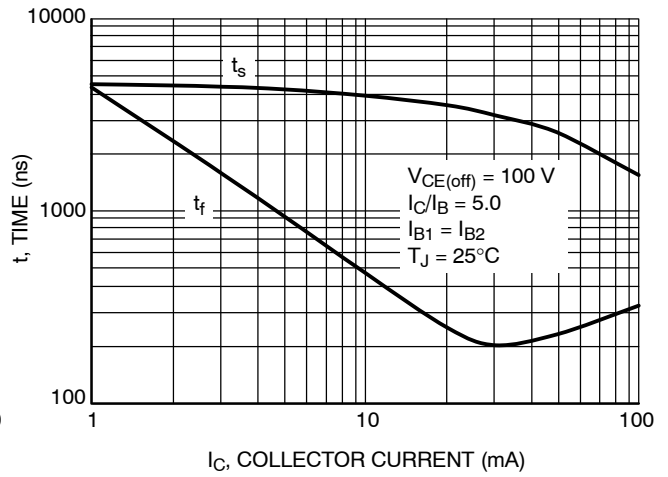


Figure 10. Turn-Off Time

# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



SCALE 4:1

## SC-70 (SOT-323) CASE 419 ISSUE R

DATE 11 OCT 2022



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH

DIM	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 BSC		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.00	2.20	0.071	0.080	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.20	0.38	0.56	0.008	0.015	0.022
H <sub>E</sub>	2.00	2.10	2.40	0.079	0.083	0.095

### GENERIC MARKING DIAGRAM



- XX = Specific Device Code
- M = Date Code
- = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.



\* For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

### SOLDERING FOOTPRINT

- |   |   |   |  |   |   |
|---|---|---|--|---|---|
| STYLE 1:<br>CANCELLED                                 | STYLE 2:<br>PIN 1. ANODE<br>2. N.C.<br>3. CATHODE     | STYLE 3:<br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR | STYLE 4:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. ANODE       | STYLE 5:<br>PIN 1. ANODE<br>2. ANODE<br>3. CATHODE          |   |
| STYLE 6:<br>PIN 1. EMITTER<br>2. BASE<br>3. COLLECTOR | STYLE 7:<br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR | STYLE 8:<br>PIN 1. GATE<br>2. SOURCE<br>3. DRAIN      | STYLE 9:<br>PIN 1. ANODE<br>2. CATHODE<br>3. CATHODE-ANODE | STYLE 10:<br>PIN 1. CATHODE<br>2. ANODE<br>3. ANODE-CATHODE | STYLE 11:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. CATHODE |

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